

Type	Hits	Search Text	DBs	Time Stamp
1	BRS	1282	349/149 (((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and substrate and electrode and switch\$4 and ((source and gate) near4 line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	1234	(((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and substrate and electrode and switch\$4 and ((source and gate) near4 line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BRS	747	(((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and substrate and electrode and switch\$4 and ((source and gate) near4 line)) and terminal ((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) near6 substrate and (pixel near3 electrode) and switch\$4 and ((source and gate) near4 line)) and ((source and terminal) near5 area)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BRS	4	(((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and (pixel near3 electrode) and switch\$4 and ((gate and source and metal\$4) near3 line)) and ((display and terminal) near5 area)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BRS	50	((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and (pixel near3 electrode) and switch\$4 and ((gate and source and metal\$4) near3 line) and insulat\$3 ((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and (pixel near3 electrode) and switch\$4 and ((gate and source and metal\$4) near3 line) and insulat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BRS	35	((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and (pixel near3 electrode) and switch\$4 and ((gate and source and metal\$4) near3 line) and insulat\$3 ((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and (pixel near3 electrode) and switch\$4 and ((gate and source and metal\$4) near3 line) and insulat\$3 and (contact near4 hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	BRS	33	((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and (pixel near3 electrode) and switch\$4 and ((gate and source and metal\$4) near3 line) and insulat\$3 and (contact near4 hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB